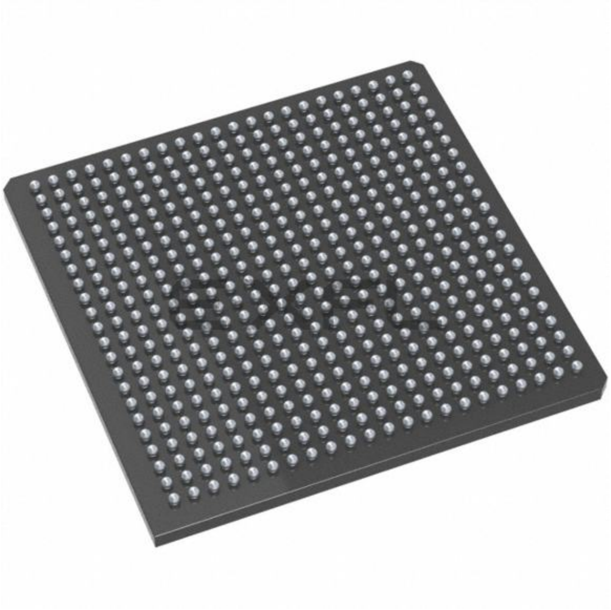


Welcome to E-XFL.COM

Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	192000
Total RAM Bits	13619200
Number of I/O	284
Number of Gates	-
Voltage - Supply	0.97V ~ 1.08V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BFBGA
Supplier Device Package	484-FPBGA (19x19)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/mpf200tls-fcvg484i

1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

1.1 Revision 1.3

Revision 1.3 was published in June 2018. The following is a summary of changes.

- The System Services section was updated. For more information, see System Services (see page 59).
- The Non-Volatile Characteristics section was updated. For more information, see Non-Volatile Characteristics (see page 51).
- The Fabric Macros section was updated. For more information, see Fabric Macros (see page 60).
- The Transceiver Switching Characteristics section was updated. For more information, see Transceiver Switching Characteristics (see page 42).

1.2 Revision 1.2

Revision 1.2 was published in June 2018. The following is a summary of changes.

- The datasheet has moved to preliminary status. Every table has been updated.

1.3 Revision 1.1

Revision 1.1 was published in August 2017. The following is a summary of changes.

- LVDS specifications changed to 1.25G. For more information, see HSIO Maximum Input Buffer Speed and HSIO Maximum Output Buffer Speed.
- LVDS18, LVDS25/LVDS33, and LVDS25 specifications changed to 800 Mbps. For more information, see I/O Standards Specifications.
- A note was added indicting a zeroization cycle counts as a programming cycle. For more information, see Non-Volatile Characteristics.
- A note was added defining power down conditions for programming recovery conditions. For more information, see Power-Supply Ramp Times.

1.4 Revision 1.0

Revision 1.0 was the first publication of this document.

2 Overview

This datasheet describes PolarFire® FPGA device characteristics with industrial temperature range (–40 °C to 100 °C T_J) and extended commercial temperature range (0 °C to 100 °C T_J). The devices are provided with a standard speed grade (STD) and a –1 speed grade with higher performance. The FPGA core supply V_{DD} can operate at 1.0 V for lower-power or 1.05 V for higher performance. Similarly, the transceiver core supply V_{DDA} can also operate at 1.0 V or 1.05 V. Users select the core operating voltage while creating the Libero project.

I/O Standard	Bank Type	VICM_RANGE Libero Setting	V_{ICM}[1,3] Min (V)	V_{ICM}[1,3] Typ (V)	V_{ICM}[1,3] Max (V)	V_{ID}[2] Min (V)	V_{ID} Typ (V)	V_{ID} Max (V)
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LVDS18	HSIO	Mid (default)	0.6	1.25	1.65	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LCMDS33	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LCMDS18	HSIO	Mid (default)	0.6	1.25	1.65	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LCMDS25	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
RSDS33	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
RSDS25	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
RSDS18[5]	HSIO	Mid (default)	0.6	1.25	1.65	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
MINILVDS33	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.3	0.6
		Low	0.05	0.4	0.8	0.1	0.3	0.6
MINILVDS25	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.3	0.6
		Low	0.05	0.4	0.8	0.1	0.3	0.6
MINILVDS18[5]	HSIO	Mid (default)	0.6	1.25	1.65	0.1	0.3	0.6
		Low	0.05	0.4	0.8	0.1	0.3	0.6
SUBLVDS33	GPIO	Mid (default)	0.6	0.9	2.35	0.1	0.15	0.3
		Low	0.05	0.4	0.8	0.1	0.15	0.3
SUBLVDS25	GPIO	Mid (default)	0.6	0.9	2.35	0.1	0.15	0.3
		Low	0.05	0.4	0.8	0.1	0.15	0.3
SUBLVDS18[5]	HSIO	Mid (default)	0.6	0.9	1.65	0.1	0.15	0.3
		Low	0.05	0.4	0.8	0.1	0.15	0.3
PPDS33	GPIO	Mid (default)	0.6	0.8	2.35	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
PPDS25	GPIO	Mid (default)	0.6	0.8	2.35	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
PPDS18[5]	HSIO	Mid (default)	0.6	0.8	1.65	0.1	0.2	0.6
		Low	0.05	0.4	0.8	0.1	0.2	0.6
SLVS33[6]	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.2	0.3
		Low	0.05	0.2	0.8	0.1	0.2	0.3
SLVS25[6]	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.2	0.3
		Low	0.05	0.2	0.8	0.1	0.2	0.3
SLVS18[5]	HSIO	Mid (default)	0.6	1.00	1.65	0.1	0.2	0.3
		Low	0.05	0.4	0.8	0.1	0.2	0.3
HCSL33[6]	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.55	1.1
		Low	0.05	0.35	0.8	0.1	0.55	1.1

I/O Standard	Bank Type	V_{OCM}[1] Min (V)	V_{OCM} Typ (V)	V_{OCM} Max (V)	V_{OD}[2] Min (V)	V_{OD}[2] Typ (V)	V_{OD}[2] Max (V)
MLVDSE25[3]	GPIO		1.25		0.396	0.442	0.453
LVPECLE33[3]	GPIO		1.65		0.664	0.722	0.755
MIPIE25[3]	GPIO		0.25		0.1	0.22	0.3

1. V_{OCM} is the output common mode voltage.
2. V_{OD} is the output differential voltage.
3. Emulated output only.

6.3.3 Complementary Differential DC Input and Output Levels

The following tables list the complementary differential DC I/O levels.

Table 16 • Complementary Differential DC Input Levels

I/O Standard	V_{DDI} Min (V)	V_{DDI} Typ (V)	V_{DDI} Max (V)	V_{ICM}[1,3] Min (V)	V_{ICM}[1,3] Typ (V)	V_{ICM}[1,3] Max (V)	V_{ID}[2] Min (V)	V_{ID} Max (V)
SSTL25I	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL25II	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
SSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
HSUL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
POD12I	1.14	1.2	1.26	0.787	0.840	0.895	0.1	
POD12II	1.14	1.2	1.26	0.787	0.840	0.895	0.1	

1. V_{ICM} is the input common mode voltage.
2. V_{ID} is the input differential voltage.
3. V_{ICM} rules are as follows:
   a. V_{ICM} must be less than V_{DDI} -0.4V;
   b. V_{ICM} + V_{ID}/2 must be <V_{DDI} + 0.4 V;
   c. V_{ICM} – V_{ID}/2 must be >VSS – 0.3 V.

Parameter	Description	Min (%)	Typ	Max (%)	Unit	Condition
Single-ended termination to V_{SS}[4, 5]	Internal parallel termination to V_{SS}	–20	120	20	Ω	V_{DDI} = 2.5 V/1.8 V/1.5 V/1.2 V
		–20	240	20	Ω	V_{DDI} = 2.5 V/1.8 V/1.5 V/1.2 V

1. Measured across P to N with 400 mV bias.
2. Thevenin impedance is calculated based on independent P and N as measured at 50% of V_{DDI}.
3. For 50 Ω/75 Ω/150 Ω cases, nearest supported values of 40 Ω/60 Ω/120 Ω are used.
4. Measured at 50% of V_{DDI}.
5. Supported terminations vary with the IO type regardless of V_{DDI} nominal voltage. Refer to Libero for available combinations.

7 AC Switching Characteristics

This section contains the AC switching characteristics of the PolarFire FPGA device.

7.1 I/O Standards Specifications

This section describes I/O delay measurement methodology, buffer speed, switching characteristics, digital latency, gearing training calibration, and maximum physical interface (PHY) rate for memory interface IP.

7.1.1 Input Delay Measurement Methodology Maximum PHY Rate for Memory Interface IP

The following table provides information about the methodology for input delay measurement.

Table 22 • Input Delay Measurement Methodology

Standard	Description	V_{L}[1]	V_{H}[1]	V_{ID}[2]	V_{ICM}[2]	V_{MEAS}[3, 4]	V_{REF}[1, 5]	Unit
PCI	PCIE 3.3 V	0	VDDI			VDDI/2		V
LVTTL33	LVTTL 3.3 V	0	VDDI			VDDI/2		V
LVCMOS33	LVCMOS 3.3 V	0	VDDI			VDDI/2		V
LVCMOS25	LVCMOS 2.5 V	0	VDDI			VDDI/2		V
LVCMOS18	LVCMOS 1.8 V	0	VDDI			VDDI/2		V
LVCMOS15	LVCMOS 1.5 V	0	VDDI			VDDI/2		V
LVCMOS12	LVCMOS 1.2 V	0	VDDI			VDDI/2		V
SSTL25I	SSTL 2.5 V Class I	V_{REF} – 0.5	V_{REF} + 0.5			V_{REF}	1.25	V
SSTL25II	SSTL 2.5 V Class II	V_{REF} – 0.5	V_{REF} + 0.5			V_{REF}	1.25	V
SSTL18I	SSTL 1.8 V Class I	V_{REF} – 0.5	V_{REF} + 0.5			V_{REF}	0.90	V
SSTL18II	SSTL 1.8 V Class II	V_{REF} – 0.5	V_{REF} + 0.5			V_{REF}	0.90	V
SSTL15I	SSTL 1.5 V Class I	V_{REF} – .175	V_{REF} + .175			V_{REF}	0.75	V
SSTL15II	SSTL 1.5 V Class II	V_{REF} – .175	V_{REF} + .175			V_{REF}	0.75	V
SSTL135I	SSTL 1.35 V Class I	V_{REF} – .16	V_{REF} + .16			V_{REF}	0.675	V
SSTL135II	SSTL 1.35 V Class II	V_{REF} – .16	V_{REF} + .16			V_{REF}	0.675	V
HSTL15I	HSTL 1.5 V Class I	V_{REF} – .5	V_{REF} + .5			V_{REF}	0.75	V
HSTL15II	HSTL 1.5 V Class II	V_{REF} – .5	V_{REF} + .5			V_{REF}	0.75	V
HSTL135I	HSTL 1.35 V Class I	V_{REF} – 0.45	V_{REF} + . 45			V_{REF}	0.675	V
HSTL135II	HSTL 1.35 V Class II	V_{REF} – .45	V_{REF} + .45			V_{REF}	0.675	V
HSTL12	HSTL 1.2 V	V_{REF} – .4	V_{REF} + .4			V_{REF}	0.60	V

Standard	Description	V_{L}[1]	V_{H}[1]	V_{ID}[2]	V_{ICM}[2]	V_{MEAS}[3, 4]	V_{REF}[1, 5]	Unit
HSUL18I	HSUL 1.8 V Class I	V_{REF} – 0.54	V_{REF} + 0.54			V_{REF}	0.90	V
HSUL18II	HSUL 1.8 V Class II	V_{REF} – 0.54	V_{REF} + 0.54			V_{REF}	0.90	V
HSUL12	HSUL 1.2 V	V_{REF} – .22	V_{REF} + .22			V_{REF}	0.60	V
POD12I	Pseudo open drain (POD) logic 1.2 V Class I	V_{REF} – .15	V_{REF} + .15			V_{REF}	0.84	V
POD12II	POD 1.2 V Class II	V_{REF} – .15	V_{REF} + .15			V_{REF}	0.84	V
LVDS33	Low-voltage differential signaling (LVDS) 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
LVDS25	LVDS 2.5 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
LVDS18	LVDS 1.8 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.900	0		V
RSDS33	RSDS 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
RSDS25	RSDS 2.5 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
RSDS18	RSDS 1.8 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
MINILVDS33	Mini-LVDS 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
MINILVDS25	Mini-LVDS 2.5 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
MINILVDS18	Mini-LVDS 1.8 V	V_{ICM} – .125	V_{ICM} + .125	0.250	1.250	0		V
SUBLVDS33	Sub-LVDS 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.900	0		V
SUBLVDS25	Sub-LVDS 2.5 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.900	0		V
SUBLVDS18	Sub-LVDS 1.8 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.900	0		V
PPDS33	Point-to-point differential signaling 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.800	0		V
PPDS25	PPDS 2.5 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.800	0		V
PPDS18	PPDS 1.8 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.800	0		V
SLVS33	Scalable low-voltage signaling 3.3 V	V_{ICM} – .125	V_{ICM} + .125	0.250	0.200	0		V

Figure 1 • Output Delay Measurement—Single-Ended Test Setup

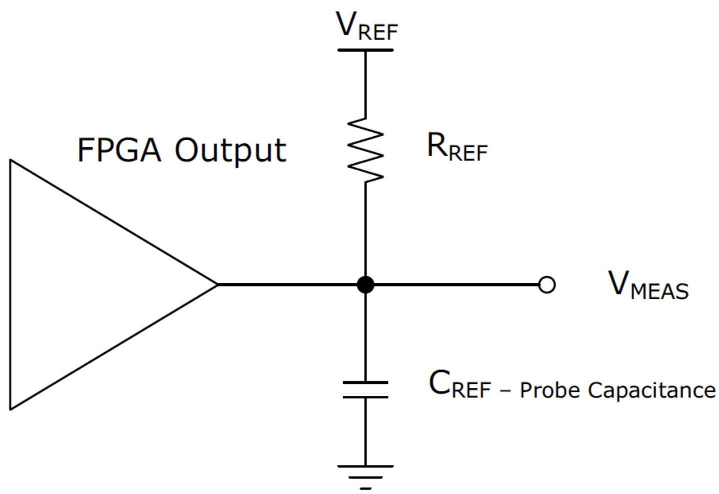
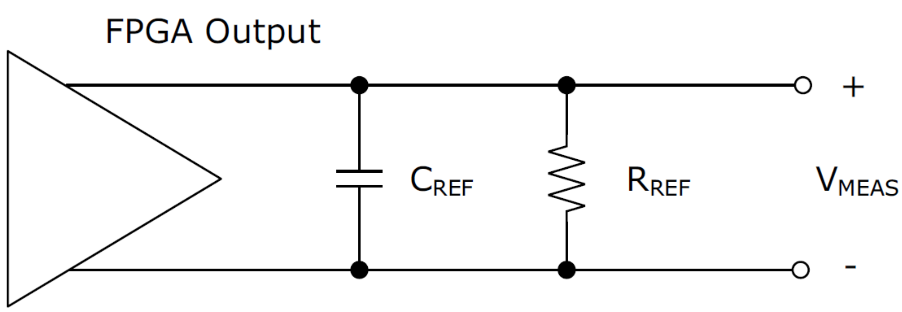


Figure 2 • Output Delay Measurement—Differential Test Setup



7.1.3 Input Buffer Speed

The following tables provide information about input buffer speed.

Table 24 • HSIO Maximum Input Buffer Speed

Standard	STD	–1	Unit
LVDS18	1250	1250	Mbps
RSDS18	800	800	Mbps
MINILVDS18	800	800	Mbps
SUBLVDS18	800	800	Mbps
PPDS18	800	800	Mbps
SLVS18	800	800	Mbps
SSTL18I	800	1066	Mbps
SSTL18II	800	1066	Mbps
SSTL15I	1066	1333	Mbps
SSTL15II	1066	1333	Mbps
SSTL135I	1066	1333	Mbps
SSTL135II	1066	1333	Mbps

Standard	STD	–1	Unit
LVCMOS12 (8 mA)	250	300	Mbps

Table 27 • GPIO Maximum Output Buffer Speed

Standard	STD	–1	Unit
LVDS25/LCMDS25	1250	1250	Mbps
LVDS33/LCMDS33	1250	1600	Mbps
RSDS25	800	800	Mbps
MINILVDS25	800	800	Mbps
SUBLVDS25	800	800	Mbps
PPDS25	800	800	Mbps
SLVSE15	500	500	Mbps
BUSLVDSE25	500	500	Mbps
MLVDSE25	500	500	Mbps
LVPECLE33	500	500	Mbps
SSTL25I	800	800	Mbps
SSTL25II	800	800	Mbps
SSTL25I (differential)	800	800	Mbps
SSTL25II (differential)	800	800	Mbps
SSTL18I	800	800	Mbps
SSTL18II	800	800	Mbps
SSTL18I (differential)	800	800	Mbps
SSTL18II (differential)	800	800	Mbps
SSTL15I	800	1066	Mbps
SSTL15II	800	1066	Mbps
SSTL15I (differential)	800	1066	Mbps
SSTL15II (differential)	800	1066	Mbps
HSTL15I	900	900	Mbps
HSTL15II	900	900	Mbps
HSTL15I (differential)	900	900	Mbps
HSTL15II (differential)	900	900	Mbps
HSUL18I	400	400	Mbps
HSUL18II	400	400	Mbps
HSUL18I (differential)	400	400	Mbps
HSUL18II (differential)	400	400	Mbps
PCI	500	500	Mbps
LVTTL33 (20 mA)	500	500	Mbps
LVCMOS33 (20 mA)	500	500	Mbps
LVCMOS25 (16 mA)	500	500	Mbps
LVCMOS18 (12 mA)	500	500	Mbps
LVCMOS15 (10 mA)	500	500	Mbps
LVCMOS12 (8 mA)	250	300	Mbps
MIPIE25	500	500	Mbps

7.1.6 User I/O Switching Characteristics

The following section describes characteristics for user I/O switching.

For more information about user I/O timing, see the *PolarFire I/O Timing Spreadsheet* (to be released).

7.1.6.1 I/O Digital

The following tables provide information about I/O digital.

Table 30 • I/O Digital Receive Single-Data Rate Switching Characteristics

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	–1 Min	–1 Typ	–1 Max	Unit	Clock-to-Data Condition
F_{MAX}	RX_SDR_G_A	Rx SDR							MHz	From a global clock source, aligned
F_{MAX}	RX_SDR_L_A	Rx SDR							MHz	From a lane clock source, aligned
F_{MAX}	RX_SDR_G_C	Rx SDR							MHz	From a global clock source, centered
F_{MAX}	RX_SDR_L_C	Rx SDR							MHz	From a lane clock source, centered

Table 31 • I/O Digital Receive Double-Data Rate Switching Characteristics

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	–1 Min	–1 Typ	–1 Max	Unit	Clock-to-Data Condition
F_{MAX}	RX_DDR_G_A	Rx DDR		335			335	MHz	MHz	From a global clock source, aligned
F_{MAX}	RX_DDR_L_A	Rx DDR		250			250		MHz	From a lane clock source, aligned
F_{MAX}	RX_DDR_G_C	Rx DDR		335			335		MHz	From a global clock source, centered
F_{MAX}	RX_DDR_L_C	Rx DDR		250			250		MHz	From a lane clock source, centered
F_{MAX} 2:1	RX_DDRX_B_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned

Table 52 • PolarFire Transceiver Transmitter Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Differential termination	V_{OTERM}		85		Ω	
	V_{OTERM}		100		Ω	
	V_{OTERM}		150		Ω	
Common mode voltage[1]	V_{OCM}	0.44 × V_{DDA}	0.525 × V_{DDA}	0.59 × V_{DDA}	V	DC coupled 50% setting
	V_{OCM}	0.52 × V_{DDA}	0.6 × V_{DDA}	0.66 × V_{DDA}	V	DC coupled 60% setting
	V_{OCM}	0.61 × V_{DDA}	0.7 × V_{DDA}	0.75 × V_{DDA}	V	DC coupled 70% setting
	V_{OCM}	0.63 × V_{DDA}	0.8 × V_{DDA}	0.83 × V_{DDA}	V	DC coupled 80% setting
Rise time[2]	T_{TxRF}	41		70	ps	20% to 80%
Fall time[2]		41		70	ps	80% to 20%
Differential peak-to-peak amplitude	V_{ODPP}		1040		mV	1000 mV setting
	V_{ODPP}		840		mV	800 mV setting
	V_{ODPP}		630		mV	600 mV setting
	V_{ODPP}		620		mV	500 mV setting
	V_{ODPP}		530		mV	400 mV setting
	V_{ODPP}		360		mV	300 mV setting
	V_{ODPP}		240		mV	200 mV setting
	V_{ODPP}		160		mV	100 mV setting
Transmit lane P to N skew[3]	T_{OSKEW}		8	15	ps	
Lane to lane transmit skew[4]	T_{LLSKEW}			75	ps	Single PLL
					ps	Multiple PLL
Electrical idle transition entry time[7]	TTxEITrEntry				ns	
Electrical idle transition exit time[7]	TTxEITrExit				ns	
Electrical idle amplitude	VTxEIpp				mV	
TXPLL lock time	T_{TXLock}			1600	PFD cycles	
Digital PLL lock time[8]	$T_{DPLLLock}$				REFCLK UIs	
Total jitter[5,6] Deterministic jitter[5,6]	T_J T_{DJ}				UI UI	Data rate ≥8.5 Gbps to 12.7 Gbps[9] (Tx V_{CO} rate 4.25 GHz to 6.35 GHz)
Total jitter[5,6] Deterministic jitter[5,6]	T_J T_{DJ}			0.28 0.07	UI UI	Data rate ≥3.2 Gbps to 8.5 Gbps (Tx V_{CO} rate 2.5 GHz to 5.0 GHz)
Total jitter[5,6] Deterministic jitter[5,6]	T_J T_{DJ}			0.28 0.07	UI UI	Data rate ≥1.6 Gbps to 3.2 Gbps (Tx V_{CO} rate 2.5 GHz to 5.0 GHz)
Total jitter[5,6] Deterministic jitter[5,6]	T_J T_{DJ}			0.13 0.02	UI UI	Data rate ≥ 800 Mbps to 1.6 Gbps (Tx V_{CO} rate 2.5 GHz to 5.0 GHz)
Total jitter[5,6] Deterministic jitter[5,6]	T_J T_{DJ}			0.06 0.01	UI UI	Data rate = 250 Mbps to 800 Mbps (Tx V_{CO} rate 2.5 GHz to 5.0 GHz)

1. Increased DC common mode settings above 50% reduce allowed V_{OD} output swing capabilities.
2. Adjustable through transmit emphasis.
3. With estimated package differences.
4. Single PLL applies to all four lanes in the same quad location with the same TxPLL.

7.5.7 CPRI

The following table describes CPRI.

Table 66 • CPRI

	Data Rate	Min	Max	Unit
Total transmit jitter	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps [1]			UI
Receive jitter tolerance	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps [1]			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section Recommended Operating Conditions (see page 6).

7.5.8 JESD204B

The following table describes JESD204B.

Table 67 • JESD204B

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	3.125 Gbps		0.35	UI
	6.25 Gbps		0.3	UI
	12.5 Gbps[1]			UI
Receive jitter tolerance	3.125 Gbps	0.56		UI
	6.25 Gbps	0.6		UI
	12.5 Gbps[1]			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05V mode. See supply tolerance in the section Recommended Operating Conditions (see page 6).

7.6 Non-Volatile Characteristics

The following section describes non-volatile characteristics.

7.6.1 FPGA Programming Cycle and Retention

The following table describes FPGA programming cycle and retention.

Table 68 • FPGA Programming Cycles vs Retention Characteristics

Programming T_J	Programming Cycles, Max	Retention Years	Retention Years at T_J
0 °C to 85 °C	1000	20	85 °C
0 °C to 100 °C	500	20	100 °C
–20 °C to 100 °C	500	20	100 °C
–40 °C to 100 °C	500	20	100 °C
–40 °C to 85 °C	1000	16	100 °C
–40 °C to 55 °C	2000	12	100 °C

Note: Power supplied to the device must be valid during programming operations such as programming and verify . Programming recovery mode is available only for in-application programming mode and requires an external SPI flash.

7.6.2 FPGA Programming Time

The following tables describe FPGA programming time.

Table 69 • Master SPI Programming Time (IAP)

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T_{PROG}	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS	17	25	s
		MPF300T, TL, TS, TLS	26	32	s
		MPF500T, TL, TS, TLS			s

Table 70 • Slave SPI Programming Time

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T_{PROG}	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS	41[1]		s
		MPF300T, TL, TS, TLS	50[1]	60	s
		MPF500T, TL, TS, TLS			s

1. SmartFusion2 with MSS running at 100 MHz, MSS_SPI_0 port running at 6.67 MHz. Bitstream stored in DDR. DirectC version 4.1.

Table 71 • JTAG Programming Time

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T_{PROG}	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS		56	s
		MPF300T, TL, TS, TLS[1]		95	s
		MPF500T, TL, TS, TLS			s

1. Programmer: FlashPro5 with TCK 10 MHz. PC Configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.

7.6.3 FPGA Bitstream Sizes

The following table describes FPGA bitstream sizes.

Table 72 • Initialization Client Sizes

Device	Plaintext	Ciphertext
MPF100T, TL, TS, TLS		
MPF200T, TL, TS, TLS	2916 KB	3006 KB
MPF300T, TL, TS, TLS	4265 KB	4403 KB
MPF500T, TL, TS, TLS		

Note: Worst case initializing all fabric LSRAM, USRAM, and UPROM.

Table 73 • Bitstream Sizes

File	Devices	FPGA	Security	SNVM (all pages)	FPGA+ SNVM	FPGA+ Sec	SNVM+ Sec	FPGA+ SNVM+ Sec
SPI	MPF100T, TL, TS, TLS							
DAT	MPF100T, TL, TS, TLS							
SPI	MPF200T, TL, TS, TLS	5.9 MB	3.4 KB	59.7 KB	5.9 MB	5.9 MB	62.2 KB	6.0 MB
DAT	MPF200T, TL, TS, TLS	5.9 MB	7.3 KB	61.2 KB	6.0 MB	5.9 MB	66.3 KB	6.0 MB
SPI	MPF300T, TL, TS, TLS	9.3 MB	3.5 KB	59.7 KB	9.6 MB	9.5 MB	62.2 KB	9.6 MB
DAT	MPF300T, TL, TS, TLS	9.3 MB	7.6 KB	61.2 KB	9.6 MB	9.5 MB	66.3 KB	9.6 MB
SPI	MPF500T, TL, TS, TLS							
DAT	MPF500T, TL, TS, TLS							

7.6.4 Digest Cycles

Digests verify the integrity of the programmed non-volatile data. Digests are a cryptographic hash of various data areas. Any digest that reports back an error raises the digest tamper flag.

Table 74 • Maximum Number of Digest Cycles

		Retention Since Programmed (N = Number Digests During that Time)[1]								
Digest T_J	Storage and Operating T_J	N ≤300	N = 500	N = 1000	N = 1500	N = 2000	N = 4000	N = 6000	Unit	Retention
–40 to 100	–40 to 100	20 × LF	17 × LF	12 × LF	10 × LF	8 × LF	4 × LF	2 × LF	°C	Years
–40 to 100	0 to 100	20 × LF	17 × LF	12 × LF	10 × LF	8 × LF	4 × LF	2 × LF	°C	Years
–40 to 85	–40 to 85	20 × LF	20 × LF	20 × LF	20 × LF	16 × LF	8 × LF	4 × LF	°C	Years
–40 to 55	–40 to 55	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	20 × LF	°C	Years

1. LF = Lifetime factor as defined by the number of programming cycles the device has seen under the conditions listed in the following table.

Parameter	Devices	Typ	Max	Unit
UFS UPERM digest run time	MPF100T, TL, TS, TLS			µs
	MPF200T, TL, TS, TLS	33.2	34.9	µs
	MPF300T, TL, TS, TLS	33.2	34.9	µs
	MPF500T, TL, TS, TLS			µs
Factory digest run time	MPF100T, TL, TS, TLS			µs
	MPF200T, TL, TS, TLS	493.6	510.1	µs
	MPF300T, TL, TS, TLS	493.6	510.1	µs
	MPF500T, TL, TS, TLS			µs

1. The entire sNVM is used as ROM.
2. Valid for user key 0 through 6.

Note: These times do not include the power-up to functional timing overhead when using digest checks on power-up.

7.6.6 Zeroization Time

The following tables describe zeroization time. A zeroization operation is counted as one programming cycle.

Table 77 • Zeroization Times for MPF100T, TL, TS, and TLS Devices

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data[1]			ms	Data erased
Time to destroy data in non-volatile memory (like new)[1, 2]			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (recoverable)[1, 3]			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (non-recoverable)[1, 4]			ms	One iteration of scrubbing
Time to scrub the fabric data[1]			s	Full scrubbing
Time to scrub the pNVM data (like new)[1, 2]			s	Full scrubbing
Time to scrub the pNVM data (recoverable)[1, 3]			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable)[1, 4]			s	Full scrubbing
Time to verify[5]			s	

1. Total completion time after entering zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

Table 78 • Zeroization Times for MPF200T, TL, TS, and TLS Devices

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data[1]			ms	Data erased
Time to destroy data in non-volatile memory (like new)[1, 2]			ms	One iteration of scrubbing

Parameter	Typ	Max	Unit	Conditions
Time to destroy data in non-volatile memory (non-recoverable)[1, 4]			ms	One iteration of scrubbing
Time to scrub the fabric data[1]			s	Full scrubbing
Time to scrub the pNVM data (like new)[1, 2]			s	Full scrubbing
Time to scrub the pNVM data (recoverable)[1, 3]			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable)[1]			s	Full scrubbing
Time to verify[5]			s	

1. Total completion time after entering zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

7.6.7 Verify Time

The following tables describe verify time.

Table 81 • Standalone Fabric Verify Times

Parameter	Devices	Max	Unit
Standalone verification over JTAG	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	53[1]	s
	MPF300T, TL, TS, TLS	90[1]	s
	MPF500T, TL, TS, TLS		s
Standalone verification over SPI	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	37[2]	s
	MPF300T, TL, TS, TLS	55[2]	s
	MPF500T, TL, TS, TLS		s

1. Programmer: FlashPro5, TCK 10 MHz; PC configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.
2. SmartFusion2 with MSS running at 100 MHz, MSS_SPI_0 port running at 6.67 MHz. DirectC version 4.1.

Notes:

- Standalone verify is limited to 2,000 total device hours ove r the industrial –40 °C to 100 °C temperature.
- Use the digest system service, for verify device time more than 2,000 hours.
- Standalone verify checks the programming margin on both the P and N gates of the push-pull cell.
- Digest checks only the P side of the push-pull gate. However, the push-pull gates work in tandem. Digest check is recommended if users believe they will exceed the 2,000-hour verify time specification.

Table 82 • Verify Time by Programming Hardware

Devices	IAP	FlashPro4	FlashPro5	BP	Silicon Sculptor	Units
MPF100T, TL, TS, TLS						
MPF200T, TL, TS, TLS	9	67	53			s
MPF300T, TL, TS, TLS	14	95	90			s

Devices	IAP	FlashPro4	FlashPro5	BP	Silicon Sculptor	Units
MPF500T, TL, TS, TLS						

Notes:

- FlashPro4 4 MHz TCK.
- FlashPro5 10 MHz TCK.
- PC configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.

Table 83 • Verify System Services

Parameter	Symbol	ServiceID	Devices	Typ	Max	Unit
In application verify by index	$T_{IAP\_Ver\_Index}$	44H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	8.2	9	s
			MPF300T, TL, TS, TLS	12.4	13	s
			MPF500T, TL, TS, TLS			s
In application verify by SPI address	$T_{IAP\_Ver\_Addr}$	45H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	8.2	9	s
			MPF300T, TL, TS, TLS	12.4	13	s
			MPF500T, TL, TS, TLS			s

7.6.8 Authentication Time

The following tables describe authentication system service time.

Table 84 • Authentication Services

Parameter	Symbol	ServiceID	Devices	Typ	Max	Unit
Bitstream Authentication	T_{BIT_AUTH}	22H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	3.3	3.7	s
			MPF300T, TL, TS, TLS	4.9	5.4	s
			MPF500T, TL, TS, TLS			s
IAP Image Authentication	T_{IAP_AUTH}	23H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	3.3	3.7	s
			MPF300T, TL, TS, TLS	4.9	5.4	s
			MPF500T, TL, TS, TLS			

7.6.9 Secure NVM Performance

The following table describes secure NVM performance.

Table 85 • sNVM Read/Write Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Plain text programming		7.0	7.2	7.9	ms	
Authenticated text programming		7.2	7.4	9.4	ms	
Authenticated and encrypted text programming		7.2	7.4	9.4	ms	
Authentication R/W 1st access from power-up overhead	T_{PUF_OVHD}		100	111	ms	From T_{FAB_READY}
Plain text read		7.67	7.79	8.2	µs	

Parameter	Symbol	Service ID	Typ	Max	Unit	Conditions
Secure NVM read	T_{SNVM_Rd}	18H				Note 1
Digital signature service raw	T_{SIG_RAW}	19H	174	187	ms	
Digital signature service DER	T_{SIG_DER}	1AH	174	187	ms	
Reserved		1BH–1FH				
PUF emulation	$T_{Challenge}$	20H	1.8	2.0	ms	
Nonce service	T_{Nonce}	21H	1.2	1.4	ms	
Bitstream authentication	TBIT_AUTH	22H				Note 4
IAP Image authentication	TIAP_AUTH	23H				Note 4
Reserved		26H–3FH				
In application programming by index	$T_{IAP\_Prg\_Index}$	42H				Note 2
In application programming by SPI address	$T_{IAP\_Prg\_Addr}$	43H				Note 2
In application verify by index	TIAP_Ver_Index	44H				Note 5
In application verify by SPI address	TIAP_Ver_Addr	45H				Note 5
Auto update	$T_{AutoUpdate}$	46H				Note 2
Digest check	T_{digest_chk}	47H				Note 3

1. See sNVM Read/Write Characteristics (see page 58).
2. See SPI Master Programming Time (see page 52).
3. See Digest Times (see page 54).
4. See Authentication Services Time (see page 58).
5. See Verify Services Time (see page 58).
6. Throughputs described are measured from SS_REQ assertion to BUSY de-assertion.

7.8 Fabric Macros

This section describes switching characteristics of UJTAG, UJTAG_SEC, USPI, system controller, and temper detectors and dynamic reconfiguration details.

7.8.1 UJTAG Switching Characteristics

The following section describes characteristics of UJTAG switching.

Table 88 • UJTAG Performance Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Condition
TCK frequency	F_{TCK}			25	MHz	

7.11 User Crypto

The following section describes user crypto.

7.11.1 TeraFire 5200B Switching Characteristics

The following table describes TeraFire 5200B switching characteristics.

Table 112 • TeraFire F5200B Switching Characteristics

Parameter	Symbol	VDD = 1.0 V STD	VDD = 1.0 V – 1	VDD = 1.05 V STD	VDD = 1.05 V – 1	Unit	Condition
Operating frequency	F_{MAX}	189		189		MHz	–40 °C to 100 °C

7.11.2 TeraFire 5200B Throughput Characteristics

The following tables for each algorithm describe the TeraFire 5200B throughput characteristics.

Note: Throughput cycle count collected with Athena TeraFire Core and RISCV running at 100 MHz.

Table 113 • AES

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
AES-ECB-128 encrypt[1]	128	515	1095
	64K	50157	933
AES-ECB-128 decrypt[1]	128	557	1760
	64K	48385	1524
AES-ECB-256 encrypt[1]	128	531	1203
	64K	58349	1203
AES-ECB-256 decrypt[1]	128	589	1676
	64K	56673	1671
AES-CBC-256 encrypt[1]	128	576	1169
	64K	52547	1169
AES-CBC-256 decrypt[1]	128	585	1744
	64K	48565	1652
AES-GCM-128 encrypt[1], 128-bit tag, (full message encrypted/authenticated)	128	1925	2740
	64K	60070	2158
AES-GCM-256 encrypt[1], 128-bit tag, (full message encrypted/authenticated)	128	1973	2268
	64K	60102	2151

1. With DPA counter measures.

Table 114 • GMAC

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
AES-GCM-256[1], 128-bit tag, (message is only authenticated)	128	1863	2211
	64K	49707	2128

SigVer, DSA-2048/SHA-256	1024	9810527	10884
	8K	9597000	10719
Key Agreement (KAS), DH-3072 (p=3072, security=256)		4920705	9338
Key Agreement (KAS), DH-3072 (p=3072, security=256)[1]		78914533	9083

1. With DPA counter measures.

Table 122 • NRBG

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
Instantiate: strength, s=256, 384-bit nonce, 384-bit personalization string		18221	2841
Reseed: no additional input, s=256		13585	1180
Reseed: 384-bit additional input, s=256		15922	1342
Generate: (no additional input), prediction resistance enabled, s= 256	128	15262	1755
	8K	27169	8223
Generate: (no additional input), prediction resistance disabled, s= 256	128	2138	1167
	8K	14045	8223
Generate: (384-bit additional input), prediction resistance enabled, s= 256	128	21299	1944
	8K	33206	8949
Generate: (384-bit additional input), prediction resistance disabled, s= 256	128	11657	1894
	8K	23564	8950
Un-instantiate		761	666

1. With DPA counter measures.